

IK Gujral Punjab Technical University
Bachelor of Technology (B. Tech. 1st Year)

BTPH104-18	Semiconductor Physics	L-3, T-1, P-0	4 Credits
Prerequisite (if any): Introduction to Quantum Mechanics desirable			
Course Objectives: The aim and objective of the course on Semiconductor Physics is to introduce the students of B. Tech. class to the formal structure of semiconductor physics so that they can use these in Engineering as per their requirement.			
Course Outcomes: At the end of the course, the student will be able to			
CO1	Understand and explain the fundamental principles and properties of electronic materials and semiconductors		
CO2	Understand and describe the interaction of light with semiconductors in terms of fermi golden rule.		
CO3	Understand and describe the impact of solid-state device capabilities and limitations on electronic circuit performance.		
CO4	Understand the design, fabrication, and characterization techniques of Engineered semiconductor materials.		
CO5	Develop the basic tools with which they can study and test the newly developed devices and other semiconductor applications.		
Detailed Syllabus:			
PART-A			
UNIT 1: Electronic materials (10 lectures)			
Free electron theory of metals, Density of states in 1D, 2D, and 3D, Bloch’s theorem for particles in a periodic potential, Energy band diagrams, Kronig-Penny model (to introduce origin of band gap), Energy bands in solids, E-k diagram, Direct and indirect bandgaps, Types of electronic materials: metals, semiconductors, and insulators, Occupation probability, Fermi level, Effective mass.			
UNIT II: Semiconductors (10 lectures)			
Intrinsic and extrinsic semiconductors, Dependence of Fermi level on carrier-concentration and temperature (equilibrium carrier statistics), Carrier generation and recombination, Carrier transport: diffusion and drift, p-n junction, Metal-semiconductor junction (Ohmic and Schottky), Semiconductor materials of interest for optoelectronic devices.			
PART-B			
UNIT III: Light-semiconductor interaction (10 lectures)			
Optical transitions in bulk semiconductors: absorption, spontaneous emission, and stimulated emission; Einstein coefficients, Population inversion, application in semiconductor Lasers; Joint density of states, Density of states for phonons, Transition rates (Fermi's golden rule), Optical loss and gain; Photovoltaic effect, Exciton, Drude model.			

UNIT IV: Measurement Techniques (10 lectures)

Measurement for divergence and wavelength using a semiconductor laser, Measurements for carrier density, resistivity, hall mobility using Four-point probe and van der Pauw method, Hot-point probe measurement, capacitance-voltage measurements, parameter extraction from diode I-V characteristics.

Reference books and suggested reading:

1. J. Singh: Semiconductor Optoelectronics: Physics and Technology, McGraw-Hill Inc. (1995).
2. B. E. A. Saleh and M. C. Teich: Fundamentals of Photonics, John Wiley & Sons, Inc., (2007).
3. S. M. Sze: Semiconductor Devices: Physics and Technology, Wiley (2008).
4. A. Yariv and P. Yeh, Photonics: Optical Electronics in Modern Communications, Oxford University Press, New York (2007).
5. P. Bhattacharya: Semiconductor Optoelectronic Devices, Prentice Hall of India (1997).
6. Ben G. Streetman: Solid State Electronics Devices, Pearson Prentice Hall.
7. D.A. Neamen, "Semiconductor Physics and Devices", Times Mirror High Education Group, Chicago, 1997.
8. E.S. Yang, "Microelectronic Devices", McGraw Hill, Singapore, 1988.
9. Online course: "Semiconductor Optoelectronics" by M R Shenoy on NPTEL.
10. Online course: "Optoelectronic Materials and Devices" by Monica Katiyar and Deepak Gupta on NPTEL.